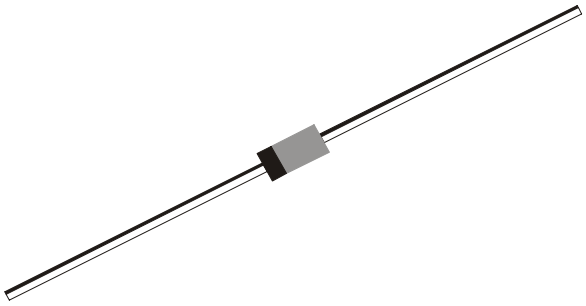
SILICON GLASS PASSIVATED 1.3 WATT ZENER DIODES

BZX85C4V7-100V

DO-41
Glass Axial Package



DESCRIPTION

1.3W Hermetically Sealed Glass Silicon Zener Diodes

ABSOLUTE MAXIMUM RATINGS (T_a=ºC)

DESCRIPTION	SYMBOL	VALUE	UNIT
Power Dissipation	*P_D	1.3	W
Operating and Storage Temperature Range	$T_{stg,}$ T_J	- 55 to+175	ºC
Maximum Lead Temperature for Soldering during 10s @ 4mm from Case	T_L	230	ºC

THERMAL RESISTANCE

Junction to Ambient in free air	*$R_{th\ (j\text{-}a)}$	110	ºC/W

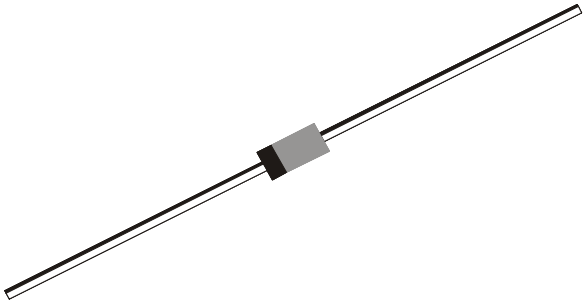
***On infinite heatsink with 4mm lead length**

ELECTRICAL CHARACTERISTICS (T_a=25ºC V_F <1.0V @ 200mA)

Device	**V_{ZT} / I_{ZT}		r_{zt} /I_{ZT}	I_{ZT}	r_{ZK} /I_{ZK}		aVZ		I_R @ 25ºC	I_R @ 150ºC	V_R	I_{ZM}	***I_{ZSM}
	MIN	MAX	MAX		MAX		MIN	MAX	Max	Max			
	(V)		(W)	(mA)	(W)	(mA)	(10^{-4}/ºC		(mA)	(mA)	(V)	(mA)	(mA)
BZX85C4V7	4.4	5.0	13	45	500	1.00	-3	4	3	10	1.0	215	1667
BZX85C5V1	4.8	5.4	10	45	500	1.00	-1	4	1	10	1.5	200	1543
BZX85C5V6	5.2	6.0	7	45	400	1.00	0	4.5	1	10	2.0	190	1389
BZX85C6V2	5.8	6.6	4	35	300	1.00	1	5.5	1	10	3.0	170	1263
BZX85C6V8	6.4	7.2	3.5	35	300	1.00	1.5	6	1	10	4.0	155	1157
BZX85C7V5	7.0	7.9	3	35	200	0.50	2	6.5	1	10	4.5	140	1055
BZX85C8V2	7.7	8.7	5	25	200	0.50	3	7	1	10	6.2	130	958
BZX85C9V1	8.5	9.6	5	25	200	0.50	3.5	7.5	1	10	6.8	120	868
BZX85C10	9.4	10.6	7	25	200	0.50	4	8	0.5	10	7.5	105	786
BZX85C11	10.4	11.6	8	20	300	0.50	4.5	8	0.5	10	8.2	97	718
BZX85C12	11.4	12.7	9	20	350	0.50	4.5	8.5	0.5	10	9.1	88	656
BZX85C13	12.4	14.1	10	20	400	0.50	5	8.5	0.5	10	10	79	591
BZX85C15	13.8	15.6	15	15	500	0.50	5.5	9	0.5	10	11	71	534
BZX85C16	15.3	17.1	15	15	500	0.50	5.5	9	0.5	10	12	66	487
BZX85C18	16.8	19.1	20	15	500	0.50	6	9	0.5	10	13	62	436
BZX85C20	18.8	21.2	24	10	600	0.50	6	9	0.5	10	15	56	393
BZX85C22	20.8	23.2	25	10	600	0.50	6	9.5	0.5	10	16	52	358
BZX85C24	22.8	25.6	25	10	600	0.50	6	9.5	0.5	10	18	47	326
BZX85C27	25.1	28.9	30	8	750	0.25	6	9.5	0.5	10	20	41	288
BZX85C30	28.0	32.0	30	8	1000	0.25	6	9.5	0.5	10	22	36	260

**** Pulse Condition : 20ms ≤ t_p≤ 50ms**

***** Rectangle wave form (t_p=10ms)**



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Device	**V_{ZT} / I_{ZT}		r_{zt} /I_{ZT}	I_{ZT}	r_{ZK} /I_{ZK}		aVZ		I_R @ 25ºC	I_R @ 150ºC	V_R	I_{ZM}	***I_{ZSM}
	MIN	MAX	MAX		MAX		MIN	MAX	Max	Max			
	(V)		(W)	(mA)	(W)	(mA)	(10^{-4}/ºC		(mA)	(mA)	(V)	(mA)	(mA)
BZX85C33	31	35	35	8	1000	0.25	6	9.5	0.5	10	24	33	238
BZX85C36	34	38	40	8	1000	0.25	6	9.5	0.5	10	27	30	219
BZX85C39	37	41	50	6	1000	0.25	6	9.5	0.5	10	30	28	203
BZX85C43	40	46	50	6	1000	0.25	6	9.5	0.5	10	33	26	181
BZX85C47	44	50	90	4	1500	0.25	6	9.5	0.5	10	36	23	167
BZX85C51	48	54	115	4	1500	0.25	6	9.5	0.5	10	39	21	154
BZX85C56	52	60	120	4	2000	0.25	6	9.5	0.5	10	43	19	139
BZX85C62	58	66	125	4	2000	0.25	6	9.5	0.5	10	47	16	126
BZX85C68	64	72	130	4	2000	0.25	6	9.5	0.5	10	51	15	116
BZX85C75	70	80	135	4	2000	0.25	6	9.5	0.5	10	56	14	104
BZX85C82	77	87	200	2.7	3000	0.25	7	12	0.5	10	62	12	96
BZX85C91	85	96	250	2.7	3000	0.25	7	12	0.5	10	68	10	87
BZX85C100	94	106	350	2.7	3000	0.25	7	12	0.5	10	75	9.4	79

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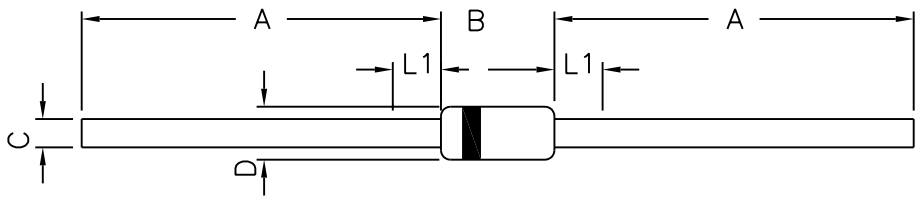
DO-41 Glass Axial Package

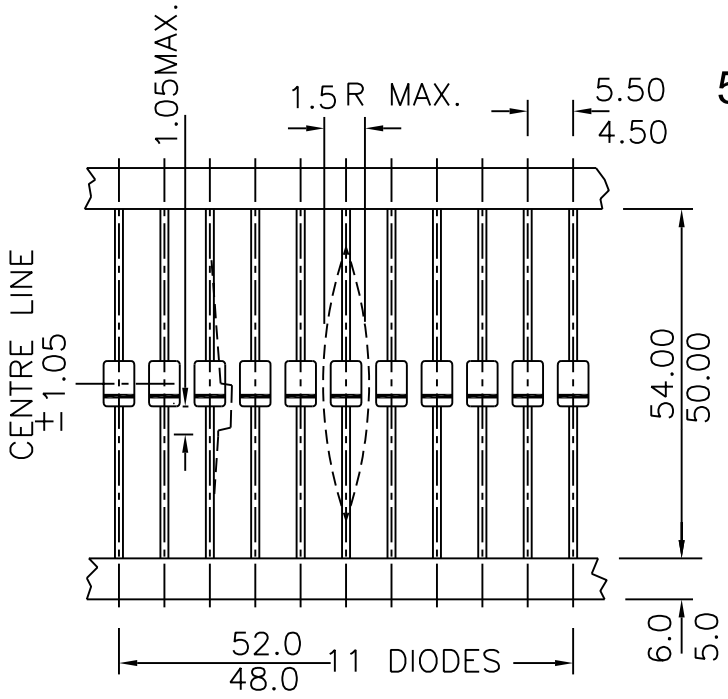


NOTES:–

Cathode is marked by Band.
All Dimensions Are In mm.

DIM	MIN	MAX
A	25.40	–
B	–	5.20
C	0.72	0.86
D	2.04	2.71
L1	–	1.27

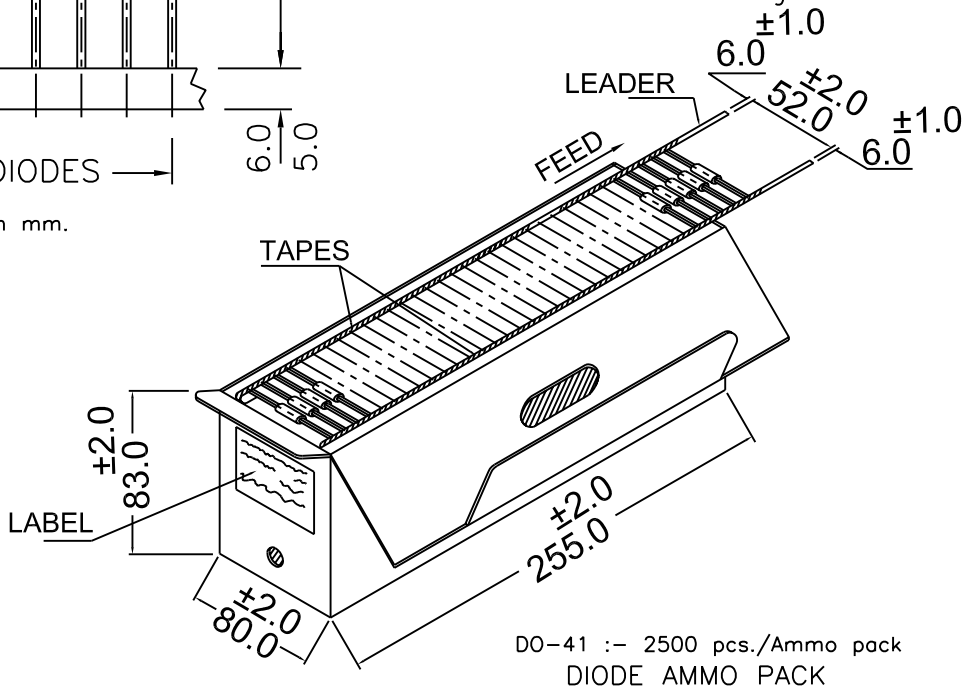
DO-41, 52mm Taping Specification



All Dimensions Are In mm.

52mm Taping Specification

1. T & A Indicates Axial Tape & Ammo packing (52 mm Tape Specing)
2. 300 mm (min) leader tape on every spool.
3. No. of empty places allowed 0.25% without consecutive empty places.
4. Ends of leads shall preferably not protrude beyond the tapes.
5. Components shall be held sufficiently in the tape or tapes so that they can not come free in normal handling.



DO–41 :– 2500 pcs./Ammo pack
DIODE AMMO PACK

on request also available in 26 mm Tape and Ammo Pack

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Qty
DO-41 T&A	2.5K/ammo box	1.04kg/2.55K pcs	10"X3.5"X3.5"	2.5K	12.7"X12.7"X20"	62.5K	30Kgs

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